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CMBT918

Total power dissipation at T _{amb} = 25°C Storage temperature Junction temperature	P _{tot} T _{stg} Tj	max –55 to max.	225 +150 150	mW ° C ° C
THERMAL CHARACTERISTICS				
$T_j = P \left(R_{th \ j-t} + R_{th \ s-a} \right) + T_{amb}$				
Thermal resistance				
from junction to ambient	R _{th j-a}		556	°C/mW
CHARACTERISTICS (at $T_A = 25^{\circ}C$ unless otherwise specified)				
Collector-emitter breakdown voltage				
$-I_C = 3 mA; -I_B = 0$	$-V_{(BR)CEO}$	min.	15	V
Collector-base breakdown voltage				
$-I_C = 1 \ \mu A; \ -I_E = 0$	-V(BR)CBO	min.	30	V
Emitter-base breakdown voltage				
$-I_E = 10 \ \mu A; \ -I_C = 0$	-V(BR)EBO	min.	3	V
Collector cut-off current				
$-V_{CB} = 15 V; -I_E = 0$	-I _{CBO}	max.	50	nA
Output capacitance at $f = 1$ MHz				
$-V_{CB} = 10 V; I_E = 0$	Cc	max.	1.7	pF
Input capacitance at $f = 1$ MHz				
$-V_{EB} = 0.5 V; I_{C}=0$	Ce	max.	2	pF
Saturation voltages				
$-I_C = 10 \ mA; \ -I_B = 1 \ mA$	-V _{CEsat}	max.	0.4	V
$I_{\mathcal{C}} = 10 \text{ mm}$, $I_{\mathcal{B}} = 1 \text{ mm}$	-V _{BEsat}	max.	1	V
D.C. current gain				
$-I_C = 3 mA; -V_{CE} = 1 V$	h _{FE}	min.	20	
Noise figure at $R_S = 50 \ \Omega$				
$-I_C = 1 mA; -V_{CE} = 6 V$				
f = 60 MHz	NF	max.	6	dB
Transition frequency				
$V_{CE} = 10$ V; $I_C = 4$ mA; $f = 100$ MHz	f_T	min.	600	MHz

Customer Notes

Disclaimer

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